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2.5-GHz, High Dynamic Range, Low-Noise Down-Converter

FEATURES

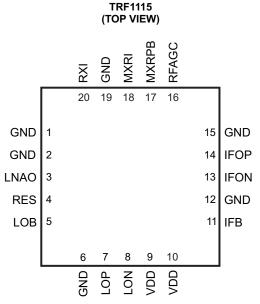
- Performs First Down-Conversion in MMDS / WCS Radio 2300 MHz to 2700 MHz
- Integrated Low Noise, Variable Gain Amplifier
- Provisions For An External Image Reject / Band Pass Filter
- Differential Mixer Provides Extra Noise Immunity
- Integrated LO Buffer Amplifier
- 20 dB of Gain With 10 dB of Gain Control
- 3-dB Noise Figure, Typical
- Input Third Order Intercept of 0 dBm, Typical
- Input P-1 dB of -5 dBm, Typical
- LO Input Power: 3 dBm

DESCRIPTION

The TRF1115 is the first of two ASICs used in the section of Texas Instruments MMDS/MDS/WCS/802.16x chipset. The TRF1115 down-converts the input frequency to an IF frequency in the range of 420 MHz to 480 MHz. The device provides a differential output that passes through a SAW filter before connecting to a second converter chip. (Note: For the performance, the Texas Instruments TRF1112 should be used to perform both the second down conversion and provide the local oscillator for the TRF1115.)

In order to provide exceptional image rejection and extra jammer rejection, the TRF1115 offers a signal path to an off-chip filter. Specifications are provided assuming an in-band 1.5-dB loss in this filter. The TRF1115 includes a differential LO buffer, mixer, and IF amplifier for improved performance. After the filter, an on-chip balun converts the signal from single-ended to differential in order to provide better noise immunity in the mixer.

DEVICE INFORMATION



P0031-03

Figure 1. TRF1115 Pin Out

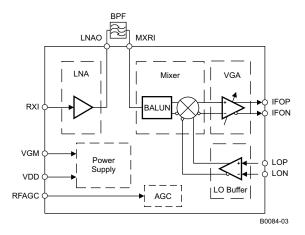


Figure 2. Block Diagram



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ABSOLUTE MAXIMUM RATINGS

| | | VALUE | UNIT |
|------------------|--|-------------|------|
| VDD | Positive DC Supply Voltage, VDD | 0.0 to +5.5 | V |
| IDD | Current consumption | 200 | mA |
| Pin | RF Input Power | 5 | dBm |
| T_J | Junction Temperature | 200 | °C |
| Pd | Power Dissipation | 1.1 | W |
| | Digital Input Pins | -0.3 to 5.5 | |
| θ_{JC} | Thermal Resistance Junction to Case ⁽¹⁾ | 9.1 | °C/W |
| T _{stg} | Storage Temperature | -40 to 105 | °C |
| T _{op} | Operating Temperature | -40 to 85 | °C |
| | Lead Temperature (40 sec max) | 260 | °C |

⁽¹⁾ Thermal resistance is junction to ambient assuming thermal pad with 16 thermal vias under package metal base. See Recommended PCB layout.

DC SPECIFICATIONS

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|----------------------------|---|-----|-----|------|------|
| VDD | Supply Voltage | | | 5 | 5.25 | V |
| IDD | Supply Current (Total) | | | 130 | 180 | mA |
| I _{LNA} | Supply Current, LNA, pin 3 | | | 30 | | mA |
| I_{LO} | Supply Current, LO, pin 9 | | | 45 | | mA |
| I _{IF} | Supply Current, IF | Pins 10 plus IF drain bias on pins 13 and 14. | | 55 | | mA |
| V _C | Gain Control Voltage | | 0 | | 2 | V |
| I _C | Gain Control Current | | 0 | | 1.2 | mA |



ELECTRICAL CHARACTERISTICS

Unless otherwise stated VDD = 5.0 V, External Filter loss = 1.5 dB, $T_{\rm A}$ = 25°C

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|---|---|------|-----|------|------|
| f _{RF} | RF input frequency | | 2300 | | 2700 | MHz |
| f_{LO} | LO input frequency | | 1820 | | 2220 | MHz |
| f _{IF} | IF output frequency | | 400 | 480 | 500 | MHz |
| G | Gain | V _C = 0 V | 16 | 18 | | dB |
| | Gain control range | V _C > 1.5 V | | 10 | | dB |
| G _{NB} | Gaub fkatbess / 6 MHz | | | | 0.2 | dB |
| NF_{HG} | Noise figure, high gain | V _C = 0 V | | 3 | 4 | dB |
| NF_{LG} | Noise figure with AGC on | V _C > 1.5 V | | 6 | 7 | dB |
| IP-1dB | Input power at 1 dB compression, high gain | V _C = 0 V, Without RF BPF | -6 | -2 | | dBm |
| IP-1dB | Input power at 1 dB compression with AGC on | V _C > 1.5 V, Without RF BPF | -1 | 2 | | dBm |
| IIP3 | Input third order intercept point, high gain | V _C = 0 V, Without RF BPF | -3 | 0 | | dBm |
| IIP3 | Input third order intercept point with AGC on | V _C > 1.5 V, Without RF BPF | 5 | 8 | | dBm |
| Z _{RF} | RF input impedance | Differential | | 50 | | Ω |
| RL _{RF} | RF input return loss | $Z = 50 \Omega$, $P_{LO} = 3 dBm$, $F_{RF} = 2500 to 2700 MHz$ | 8 | 10 | | dB |
| Z _{LO} | LO input impedance | Differential | | 100 | | Ω |
| P_{LO} | LO input power | Referenced to 100 Ω differential | 0 | 3 | 6 | dB |
| RL_{LO} | LO input return loss | Differential, with external matching circuit. LO input = 3 dBm | -10 | -12 | | dB |
| Z _{IF} | IF output impedance | Differential | | 100 | | Ω |
| RL _{IF} | IF1 output return loss | Differential, with external matching circuit | -7 | -10 | | dB |
| | LO to RF leakage, differential | LO input = 3 dBm, V _C = 0 V | -35 | -45 | | dBm |
| | LO to IF1 leakage, differential | LO input = 3 dBm, V _C = 0 V | -40 | -50 | | dBm |
| | RF to IF1 isolation, differential | LO input = 3 dBm, V _C = 0 V | 35 | 45 | | dBc |
| | RF to LO insolation, differential | LO input = 3 dBm, V _C = 0 V | | 25 | | dBc |

TERMINAL FUNCTIONS

| TERMINAL | | 1/0 | TVDE | DESCRIPTION |
|------------------------|------|-----|------------------|---|
| NO. | NAME | 1/0 | TYPE | DESCRIPTION |
| 1, 2, 6, 12, 15, 19 | GND | | | Ground |
| 3 | LNAO | 0 | Analog/P ower | Output of LNA, before mixer, Also provides DC bias to FET. Apply 5 V bias thru bias network. |
| 4 | RES | | | Reserved. Do not connect or ground this pin. |
| 5 | LOB | | | Not connected for normal operation. Internal bias for LO buffer. Normal voltage at this pin is 3.0 to 3.2 V. Do not ground this pin or connect. |
| 7 | LOP | I | Analog | LO input, Positive, ac coupled internally |
| 8 | LON | - 1 | Analog | LO input, Negative, ac coupled internally |
| 9 | VDD | - 1 | Power | DC bias for LO Buffer +5 V |
| 10 | VDD | - 1 | Power | DC bias for IF circuit +5 V |
| 11 | IFB | | | Not connected for normal operation. Internal bias for IF circuitry Normal voltage at this pin is 2.8 to 3.0 V. Do not ground this pin or connect. |
| 13 | IFON | 0 | Analog/P ower | IF output, negative, and dc bias for IF amplifier. Apply +5 V through bias network. |
| 14 | IFOP | 0 | Analog/P ower | IF output, Positive, and dc bias for IF amplifier. Apply +5 V through bias network. |



TERMINAL FUNCTIONS (continued)

| TEF | TERMINAL | | TERMINAL | | TERMINAL | | TERMINAL | | TERMINAL | | TERMINAL | | TERMINAL | | TVDE | DESCRIPTION |
|------|----------|----------|----------|--|----------|--|----------|--|----------|--|----------|--|----------|--|------|-------------|
| NO. | NAME | I/O TYPE | | DESCRIPTION | | | | | | | | | | | | |
| 16 | RFAGC | I | Analog | Input voltage for gain control: $V_C=0$ to 1.5 V Maximum gain at $V_C=0$ V Minimum gain at $V_C=1.5$ V | | | | | | | | | | | | |
| 17 | MXRPB | | | Not connected for normal operation. Internal bias for mixer circuitry. Normal voltage at this pin is 1.8 V to 2.5 V. Do not ground this pin or connect to any other pin. | | | | | | | | | | | | |
| 18 | MXRI | I | Analog | Input to RF mixer, ac coupled, 50 Ω | | | | | | | | | | | | |
| 20 | RXI | I | Analog | RF input, ac coupled, 50 Ω | | | | | | | | | | | | |
| Back | GND | | | Back of package has metal base that must be grounded for thermal and RF performance. | | | | | | | | | | | | |

TYPICAL CHARACTERISTICS

TYPICAL DATA

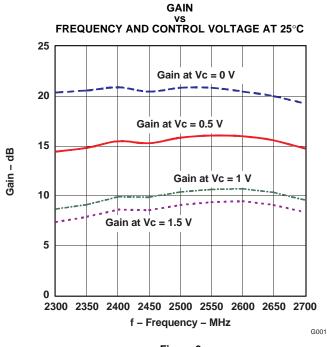


Figure 3.

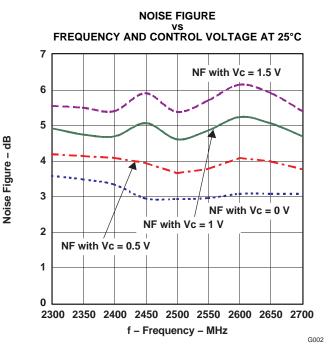


Figure 4.



TYPICAL CHARACTERISTICS (continued)

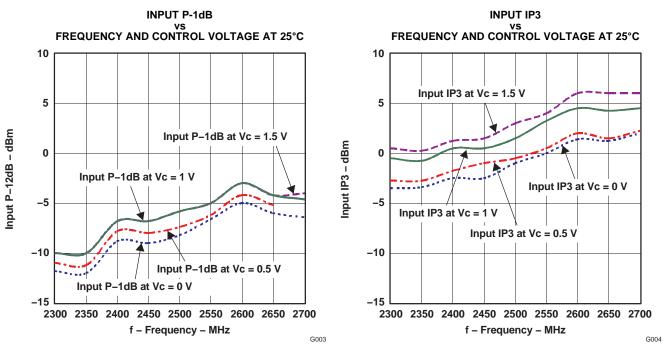
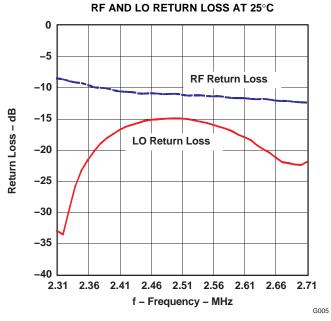
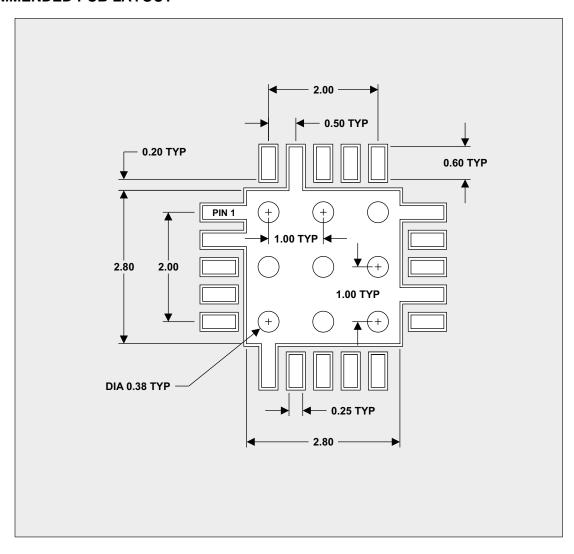


Figure 5. Figure 6.





RECOMMENDED PCB LAYOUT



Solder Mask. No Solder Mask Under Chip, On Lead Pads or On Ground Connections.

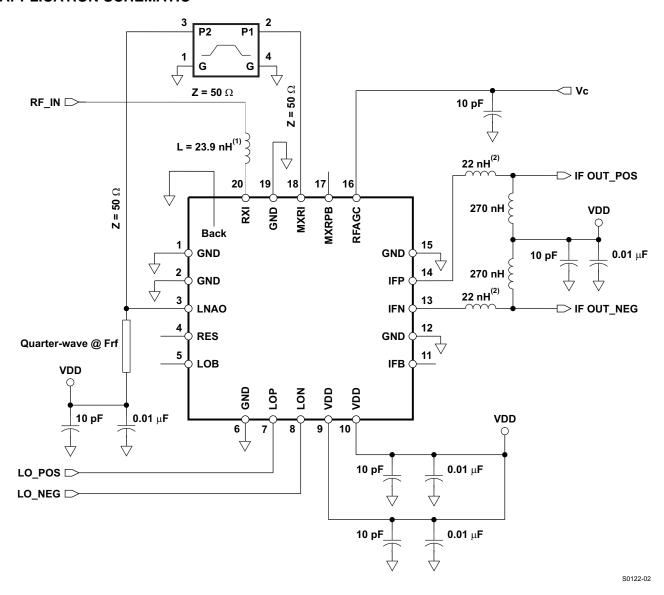
Notes: 9 Via Holes, Each 0.38 mm. DIMENSIONS in mm

M0022-04

A. Four layer Board, Starting material: two: 10 mil core FR4 with 1 oz copper, both sides, pressed with 8 mil thick prepreg. Via plating ½ oz copper plate, final plate White immersion tin. Final thickness: 0.033" to 0.037" thick.



APPLICATION SCHEMATIC





APPLICATION INFORMATION

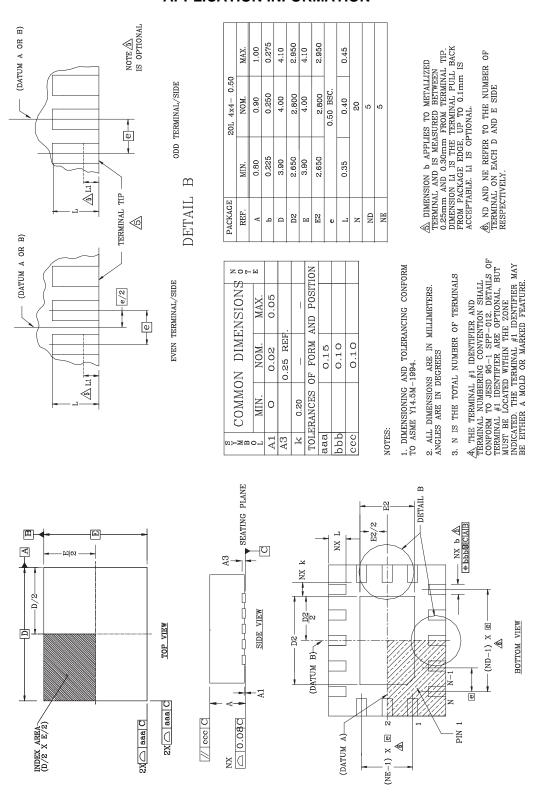


Figure 8. Package Outline: 4 mm x 4 mm LPCC 20-Pin Leadless Package





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PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|------------------|-----------------------|--------------|--------------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| TRF1115IRGPR | ACTIVE | QFN | RGP | 20 | 2500 | Green (RoHS & no Sb/Br) | CU SN | Level-3-260C-168 HR | |
| TRF1115IRGPRG3 | ACTIVE | QFN | RGP | 20 | 2500 | Green (RoHS & no Sb/Br) | CU SN | Level-3-260C-168 HR | |
| TRF1115IRGPT | ACTIVE | QFN | RGP | 20 | 250 | Green (RoHS & no Sb/Br) | CU SN | Level-3-260C-168 HR | |
| TRF1115IRGPTG3 | ACTIVE | QFN | RGP | 20 | 250 | Green (RoHS & no Sb/Br) | CU SN | Level-3-260C-168 HR | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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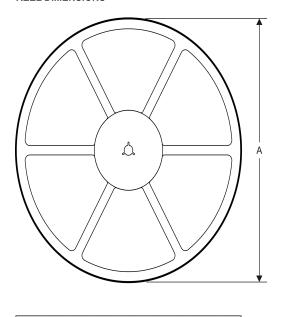
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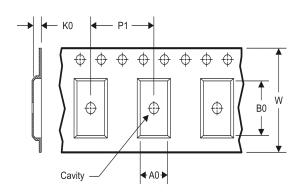
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



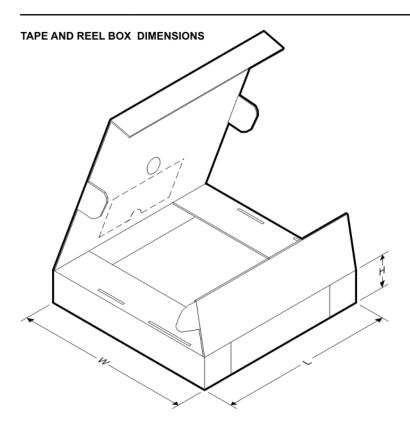
| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

TAPE AND REEL INFORMATION

*All dimensions are nominal

| 7 til dilliononono aro momina | | | | | | | | | | | | |
|-------------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| TRF1115IRGPR | QFN | RGP | 20 | 2500 | 330.0 | 12.4 | 4.3 | 4.3 | 1.5 | 8.0 | 12.0 | Q2 |
| TRF1115IRGPT | QFN | RGP | 20 | 250 | 330.0 | 12.4 | 4.3 | 4.3 | 1.5 | 8.0 | 12.0 | Q2 |

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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TRF1115IRGPR | QFN | RGP | 20 | 2500 | 338.1 | 338.1 | 20.6 |
| TRF1115IRGPT | QFN | RGP | 20 | 250 | 338.1 | 338.1 | 20.6 |

RGP (S-PVQFN-N20) PLASTIC QUAD FLATPACK NO-LEAD 4,15 3,85 A В 15 11 10 16 4,15 3,85 20 6 Pin 1 Index Area Top and Bottom 0,20 Nominal Lead Frame 1,00 0,80 Seating Plane _____0,08 C Seating Height $\frac{0.05}{0.00}$ C THERMAL PAD 20 SIZE AND SHAPE 4X 2,00 SHOWN ON SEPARATE SHEET 16 10 0,50 15 $20X \frac{0,30}{0,18}$

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.

0,10 M C A B 0,05 M C

4203555/G 07/11

🖒 Check thermal pad mechanical drawing in the product datasheet for nominal lead length dimensions.



Bottom View

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| roducts | Applications | |
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